

DESCRIPTION:

This document describes Aplus 64M x 72-bit 512MB DDR2-533 CL4 SDRAM (Synchronous DRAM) Registered ECC memory module. The components on this module include nine 64M x 8-bit (4Banks) DDR2-533 SDRAM in FBGA packages. This 240-pin DIMM uses gold contact fingers and requires +1.8V. The electrical and mechanical specifications are as follows:

FEATURES:

- JEDEC standard 1.8V \pm 0.1V Power supply
- All inputs and outputs SSTL_1.8 compatible
- Max clock Freq: 267Mhz
- Double-data-rate architecture; two data transfers per clock cycle
- Bidirectional data strobe (DQS)
- Differential clock inputs (CK and CK)
- DLL aligns DQ and DQS transition with CK transition
- Programmable Read latency 4 (clock)
- Burst Length: 4,8 (Interleave/nibble sequential)
- Programmable Burst type (sequential & interleave)
- Timing Reference: CL-tRCD-tRP (4-4-4)
- Edge aligned data output, center aligned data input
- Auto & Self refresh, 7.8us refresh interval (8K/64ms refresh)
- Error Check Correction (ECC) Capability
- High temperature self-refresh Entry enable features
- PASR (Partial array self refresh)
- OCD (Off-chip driver impedance adjustment)
- ODT (On-die termination)
- Serial presence detect with EEPROM

PERFORMANCE:

Clock Cycle Time (tCK)	3.75ns (min.) /8ns (max.)
Row Cycle Time (tRC)	55ns (min.)
Refresh Row Cycle Time (tRFC)	105ns (min.)
Row Active Time (tRAS)	40ns (min.) /70,000ns (max.)
Operating Temperature	0°C ~ 85°C
Storage Temperature	-55°C ~ +100°C

